PolarHV[™] HiPerFET **Power MOSFET**

IXFP 5N50PM

(Electrically Isolated Tab)

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Diode

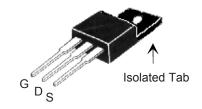


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	Js

Symbol Test Conditions Maximum Ratings $T_{.} = 25^{\circ} \text{ C to } 150^{\circ} \text{ C}$ 500 V_{DSS} V_{DGR} $T_J = 25^{\circ} \text{ C to } 150^{\circ} \text{ C}; R_{GS} = 1 \text{ M}\Omega$ 500 V $\mathbf{V}_{\mathrm{GSS}}$ Continuous ± 30 V Transient ± 40 V_{GSM} ٧ I_{D25} $T_c = 25^{\circ}C$ 3.2 Α $T_{\rm C}$ = 25° C, pulse width limited by $T_{\rm IM}$ 10 Α I_{DM} $T_{\rm C} = 25^{\circ} \, \rm C$ \mathbf{I}_{AR} 5 Α $T_{\rm c} = 25^{\circ} {\rm C}$ 15 mJ $T_{\rm C}^{\circ} = 25^{\circ} \, \rm C$ 150 mJ dv/dt $I_{S} \leq I_{DM}$, di/dt ≤ 100 A/ μ s, $V_{DD} \leq V_{DSS}$, 10 V/ns $T_J \leq 150^{\circ} C$, $R_G = 30 \Omega$ $T_c = 25^{\circ}C$ $\mathbf{P}_{\scriptscriptstyle \mathrm{D}}$ 38 W T_{J} -55 ... +150 °С $\mathbf{T}_{\mathrm{JM}}^{\mathrm{T}}$ $^{\circ}\text{C}$ 150 $\mathsf{T}_{\underline{\mathsf{stg}}}$ -55 ... +150 $^{\circ}\text{C}$ T_L 1.6 mm (0.062 in.) from case for 10 s °C 300 T_{SOLD} Plastic body for 10 s 260 $^{\circ}C$ M, 1.13/10 Nm/lb.in. Mounting torque

OVERMOLDED TO-220 (IXTP...M) OUTLINE

V_{DSS}



500

≤ 200 ns

≤

Features

g

- Plastic overmolded tab for electrical isolation
- Fast intrinsic diode
- International standard package
- Unclamped Inductive Switching (UIS)
- Low package inductance
 - easy to drive and to protect

Symbol (T _J = 25° C, u		Ch Min.	istic Val Max.		
BV _{DSS}	$V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$		500		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 500 \mu A$		3.0	5.5	V
I _{GSS}	$V_{GS} = \pm 30 \ V_{DC}, \ V_{DS} = 0$			±100	nA
I _{DSS}	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$	T _J = 125° C		5 50	μA μA
R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_{D} = 2.5 \text{ A}$ Note 1			1.4	Ω

Advantages

- Easy to mount
- Space savings
- High power density

Weight



Symbo	ol	Test Conditions	$C_J = 25^{\circ} C$, unless Min.	haracte s otherw ryp.		ecified)
\mathbf{g}_{fs}		V_{DS} = 10 V; I_{D} = 2.5 A, Note 1	3.0	4.7		S
C _{iss})			620		pF
$\mathbf{C}_{\mathrm{oss}}$	}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MH}$	z	72		pF
\mathbf{C}_{rss}	J			6.3		pF
t _{d(on)})			28		ns
t,		$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} =$	5 A	28		ns
$\mathbf{t}_{d(off)}$		$R_{_{G}}$ = 30 Ω (External)		65		ns
t _f)			26		ns
$Q_{g(on)}$)			12.6		nC
\mathbf{Q}_{gs}	}	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = 2$	2.5 A	4.3		nC
\mathbf{Q}_{gd}	J			5.0		nC
R _{thJC}					3.3	°C/W

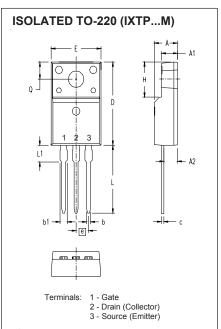
Source-Drain Die	ode
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Characteristic Values (T₁ = 25° C unless otherwise specified)

Symbol	Test Conditions	Min.	Тур.	Max.	
I _s	$V_{GS} = 0 V$			5	Α
I _{SM}	Repetitive			15	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0$ V, Note 1			1.5	V
t _{rr} Q _{RM} I _{RM}	$I_F = 5 \text{ A}$, -di/dt = 100 A/ μ s, $V_R = 100 \text{ V}$, $V_{GS} = 0 \text{ V}$		0.15 1	200	ns μC A

Notes:

1) Pulse test, t ≤300 µs, duty cycle d≤ 2 %



MYZ	INCHES		MILLIMETERS		
2114	MIN	MAX	MIN	MAX	
Α	.177	.193	4.50	4.90	
A1	.092	.108	2.34	2.74	
A2	.101	.117	2.56	2.96	
b	.028	.035	0.70	0.90	
b1	.050	.058	1.27	1.47	
С	.018	.024	0.45	0.60	
D	.617	.633	15.67	16.07	
E	.392	.408	9.96	10.36	
е	.100 BSC		2.54 BSC		
Н	.255	.271	6.48	6.88	
L	.499	.523	12.68	13.28	
L1	.119	.135	3.03	3.43	
ØΡ	.121	.129	3.08	3.28	
Q	.126	.134	3.20	3.40	

PRELIMINARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from data gathered during objective characterizations of preliminary engineering lots; but also may yet contain some information supplied during a pre-production design evaluation. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

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IXYS MOSFETs and IGBTs are covered by 4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065 B1 6,683,344 6,727,585 one or moreof the following U.S. patents: 5,017,508 6,710,405B2 4,850,072 5,063,307 5,381,025 6,259,123 B1 6,534,343 6,759,692 4,881,106 5,034,796 5,187,117 5,486,715 6,306,728 B1 6,583,505 6,710,463 6,771,478 B2